

RKZ6.8Z4MFAKT

Silicon Planar Zener Diode for Surge Absorption

REJ03G1351-0100 Rev.1.00 Feb 22, 2006

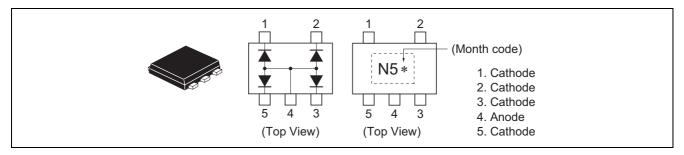
Features

- RKZ6.8Z4MFAKT has four devices in a monolithic, and can absorb surge.
- Low capacitance (C = 4.0 pF Typ) and can protect ESD of signal line.
- VSON-5 Package is suitable for high density surface mounting.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code	
RKZ6.8Z4MFAKT	N5	VSON-5	PUSN0005ZB-A	

Pin Arrangement



Month Code

	Assemble		
Month of Manufacture	JAPAN	MALAYSIA	
January	Α	1	
February	В	2	
March	С	3	
April	D	4	
May	E	5	
June	F	6	

	Assemble		
Month of Manufacture	JAPAN	MALAYSIA	
July	G	7	
August	Н	8	
September	J	9	
October	K	W	
November	L	X	
December	М	Υ	

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Power dissipation	Pd *	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note: Four device total, See Fig.2.

Electrical Characteristics *1

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Zener voltage	Vz	6.47	_	7.00	V	$I_Z = 5$ mA, 40 ms pulse
Reverse current	I _R	_	_	2	μΑ	V _R = 3.5 V
Capacitance	С	_	4.0	4.5	pF	$V_R = 0 V, f = 1 MHz$
Dynamic resistance	r _d	_	_	30	Ω	$I_Z = 5 \text{ mA}$
ESD-Capability *2, *3	_	8	_	_	kV	$C = 150 \text{ pF}, R = 330 \Omega$, Both forward and
						reverse direction 10 pulse

Notes: 1. Per one device.

- 2. Failure criterion ; $I_R > 2 \mu A$ at $V_R = 3.5 \ V$.
- 3. Between cathode and anode.

Main Characteristic

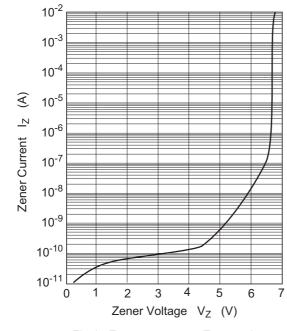


Fig.1 Zener current vs. Zener voltage

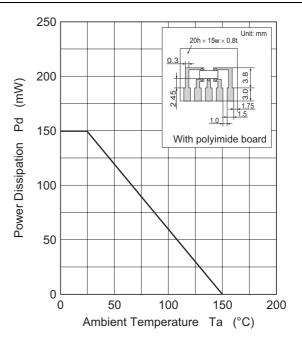


Fig.2 Power Dissipation vs. Ambient Temperature

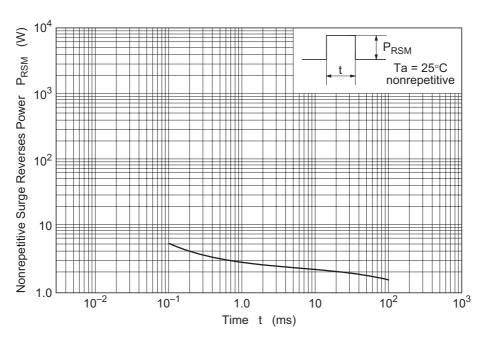
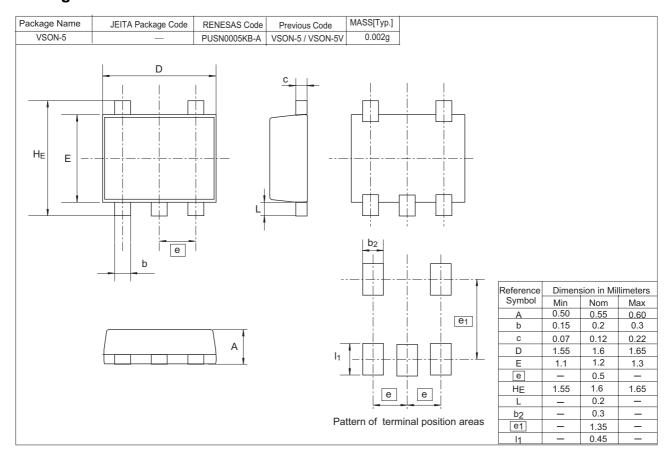


Fig.3 Surge Reverse Power Ratings

Package Dimensions



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